

| | Type | L # | Hits | Search Text | DBs |
|---|------|-----|------|--|--|
| 1 | BRS | L1 | 2 | "6744482".pn. | US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B |
| 2 | BRS | L2 | 0 | (oixel near electrode\$1) near25 (electroluminescence or el) | US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B |
| 3 | BRS | L3 | 1202 | (pixel near electrode\$1) near25 (electroluminescence or el) | US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B |
| 4 | BRS | L4 | 0 | (pixel near electrode\$1) near25 (electroluminescence) | US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B |

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|---|------|-----|------|--|--|
| 5 | BRS | L5 | 0 | (pixel near electrode\$1) near25 (electro- luminescence) | US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B |
| 6 | BRS | L6 | 1202 | (pixel near electrode\$1) near25 (el) | US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B |
| 7 | BRS | L7 | 518 | ((pixel near electrode\$1) near25 (el)) near25 (hole\$1 or aperture\$1 or recess\$2 or via\$1 or open\$3) | US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B |
| 8 | BRS | L8 | 1 | ((((pixel near electrode\$1) near25 (el)) near25 (hole\$1 or aperture\$1 or recess\$2 or via\$1 or open\$3)) near25 (silicon near nitride or sin) | US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B |

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|----|------|-----|------|---|--|
| 9 | BRS | L9 | 383 | ((pixel near electrode\$1) near25 (el)) near25 (hole\$1 or aperture\$1 or recess\$2 or via\$1 or open\$3)) and (silicon near nitride) | US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B |
| 10 | BRS | L10 | 1 | ((pixel near electrode\$1) near25 (el)) near25 (hole\$1 or aperture\$1 or recess\$2 or via\$1 or open\$3)) same (silicon near nitride) | US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B |
| 11 | BRS | L11 | 401 | ((pixel near electrode\$1) near25 (el)) near25 (hole\$1 or aperture\$1 or recess\$2 or via\$1 or open\$3)) and (silicon near nitride or sin) | US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B |
| 12 | BRS | L12 | 2 | ((((pixel near electrode\$1) near25 (el)) near25 (hole\$1 or aperture\$1 or recess\$2 or via\$1 or open\$3)) and (silicon near nitride or sin)) near35 (substrate) | US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B |

| | Type | L # | Hits | Search Text | DBs |
|----|------|-----|------|--|--|
| 13 | BRS | L13 | 0 | (((((pixel near electrode\$1) near25 (el)) near25 (hole\$1 or aperture\$1 or recess\$2 or via\$1 or open\$3)) and (silicon near nitride or sin)) near35 (wafer) | US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B |
| 14 | BRS | L14 | 0 | ("2004/0207331").URPN. | USPAT |